NSN 5961-00-238-3677

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-238-3677 **Inclosure Material:** Glass **Overall Length:** 0.710 millimeters **Terminal Length:** 0.210 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.209 millimeters **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 50.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 175.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 200.0 degrees celsius case **Special Features:** High frequency low power silicon npn bjt; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli